



# First prototype of finely segmented HPK AC-LGAD detectors

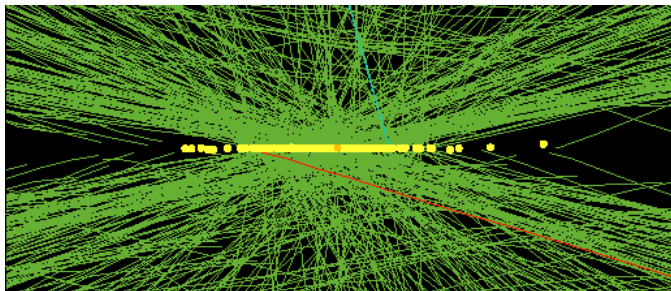
*Sayuka Kita, Tatsuki Ueda, Takanori Suzuki, Kazuhiko Hara  
(Tsukuba)*

*Koji Nakamura (KEK)*

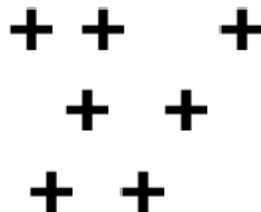
*Hamamatsu Photonics K.K.*

# Introduction

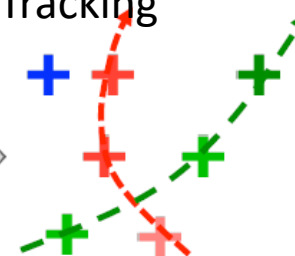
- Most serious issue in the future hadron collider should be a number of **multiple interactions** per bunch crossing.
  - About 140-200 at the HL-LHC and 1400 (FCC) in future colliders.
  - Idea to solve the issue?
    1. **Pixel size**: Construct smaller pixel size detector and make better vertices separation → **May be hard to improve 10 times...**
    2. **Time resolution**: If we could use timing information for the hit in the track, may have better track finding using the information. → If the timing resolution is less than  $1\text{cm}/c = 30\text{ps}$  it should help a lot. **To do this, detector should have both spatial and timing resolution**




Detector Hit



Tracking



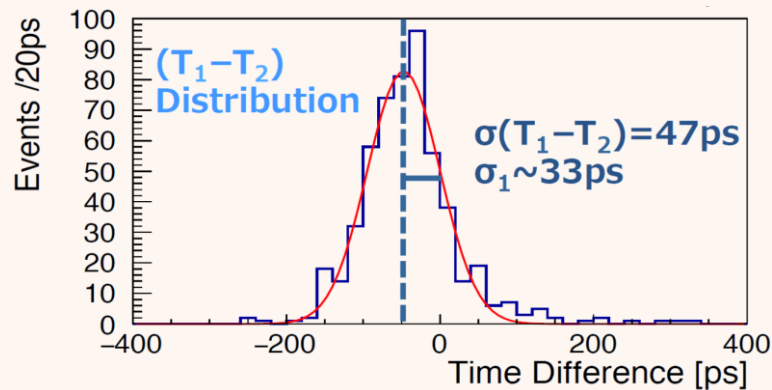
# Introduction

- **Low Gain Avalanche Diode (LGAD) Detector is getting mature technology as precise timing detector ( $\sim 30\text{ps}$  resolution) for MIP particle detection.**
- **30ps ( $\sim 1\text{cm}$  by speed of light) resolution**, there are a lot of application possibilities to the interdisciplinary worlds.
  - Biology, Medical and Industry area
- To apply this technology to High Energy collider inner tracking detector to improve physics performance :
  - **Need  $\sim 10\mu\text{m}$  spatial resolution.**  **Main topic in this presentation**
  - Need  $\sim 10^{16} \text{ n}_{\text{eq}}/\text{cm}^2$  radiation tolerance (in case of hadron collider)
  - Need small/Front-end readout electronics (i.e. ASIC with high speed Amplifier)

# History of HPK LGAD detector development

## First LGAD detector by HPK in 2015

First PAD detector worked and evaluated 33ps timing resolution !!

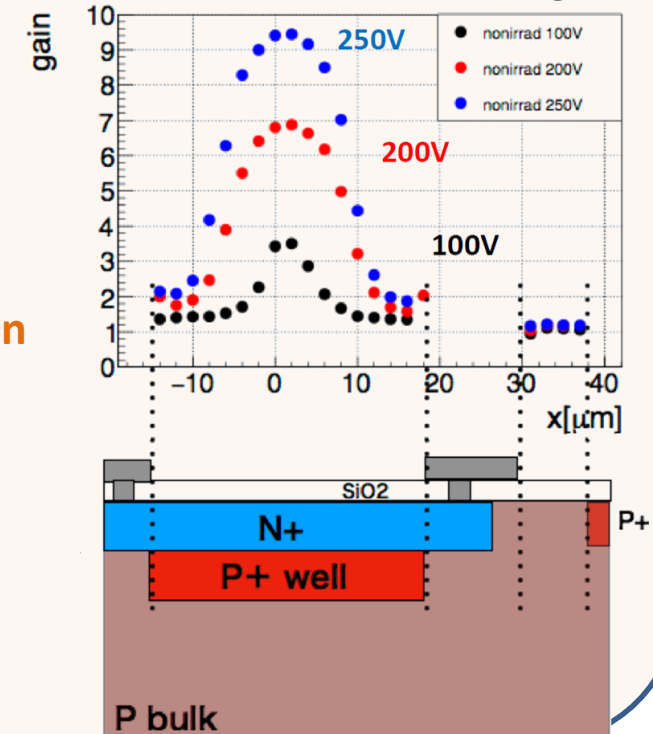
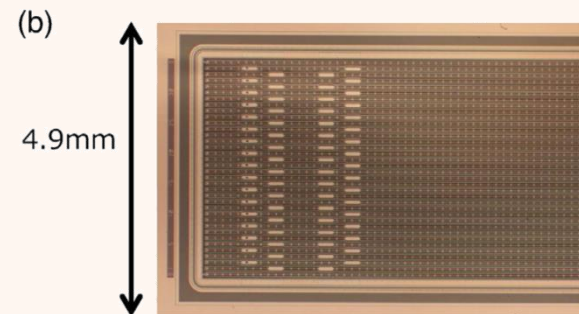


*S.Wada et.al. NIMA Volume 924, Pages 380-386 doi:10.1016/j.nima.2018.09.143*

*K.Onaru et.al. NIMA Volume 985, 164664 doi:10.1016/j.nima.2020.164664*

First Strip detector had gain un-uniformity

80um pitch strip detector :  
only 20um region (25%) have gain



## Second LGAD detector by HPK in 2018

*R. Padilla et. al. 2020 JINST 15 P10003 doi:10.1088/1748-0221/15/10/P10003*

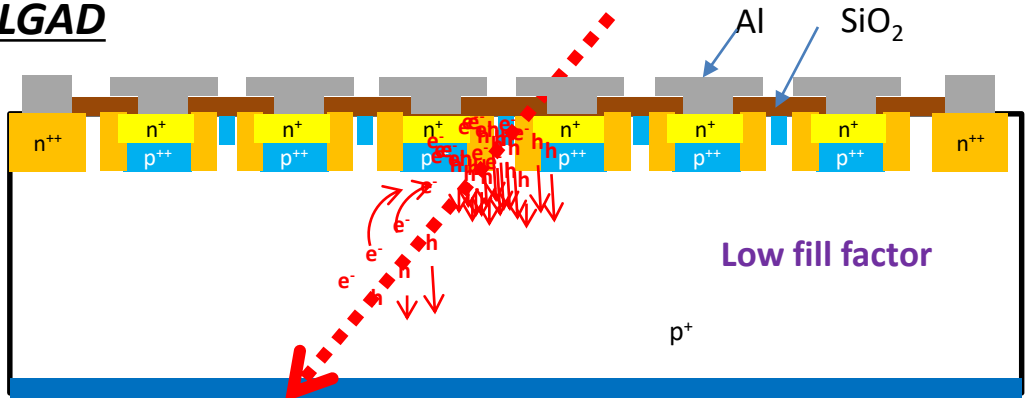
ATLAS/CMS run for HL-LHC timing detector

Optimization of process/doping profile/active thickness etc. by ATLAS/CMS collaboration

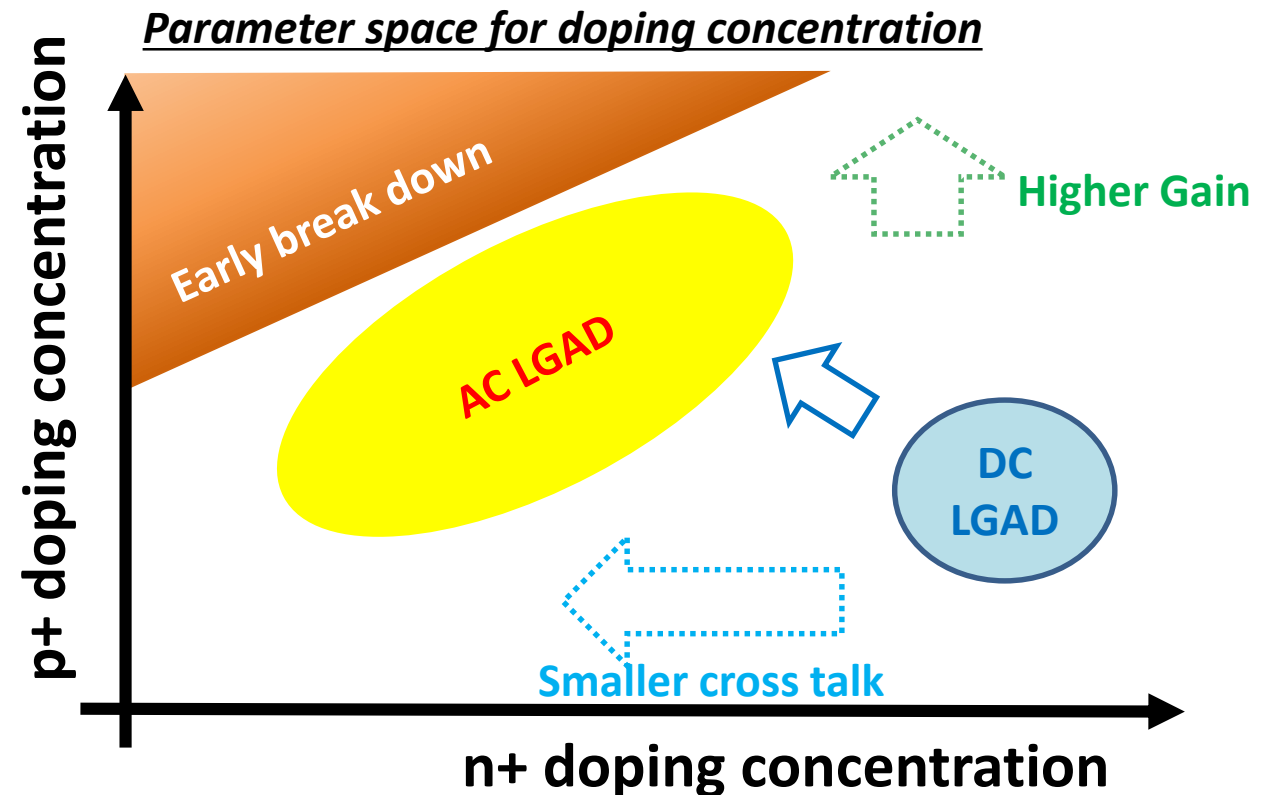
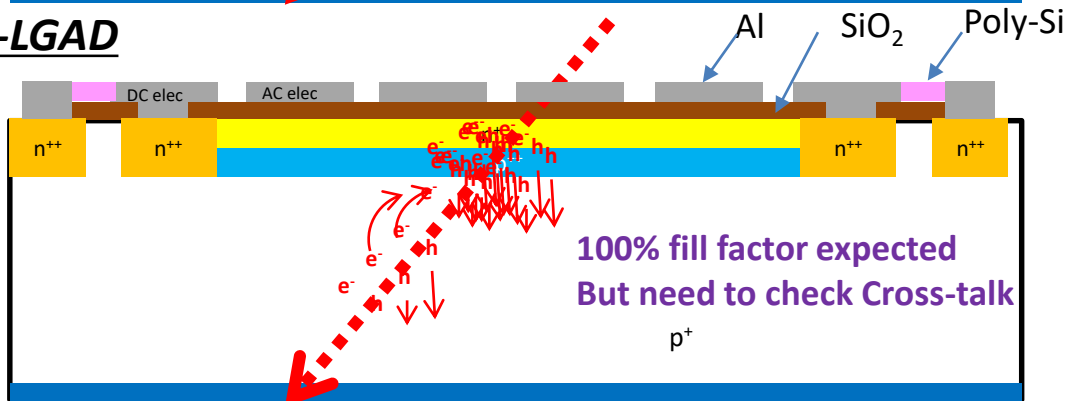
# Idea of AC-LGAD detector

- Original segmented LGAD detector has a quite low fill factor (25%) due to separated gain layers.
- Single gain layer with AC-coupled electrodes may solve the issue.
  - Lower  $n^+$  doping concentration (= higher resistivity) to reduce cross talk. How much lower?

DC-LGAD



AC-LGAD

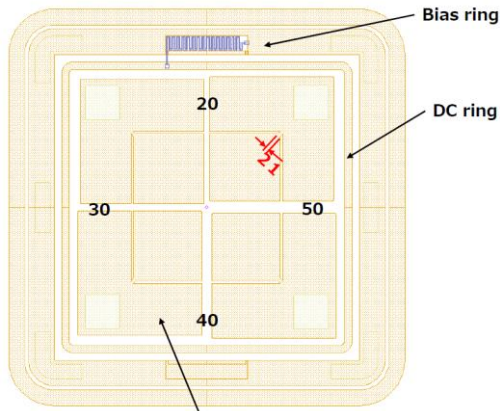


# First AC-LGAD mask at HPK

50um Active thickness

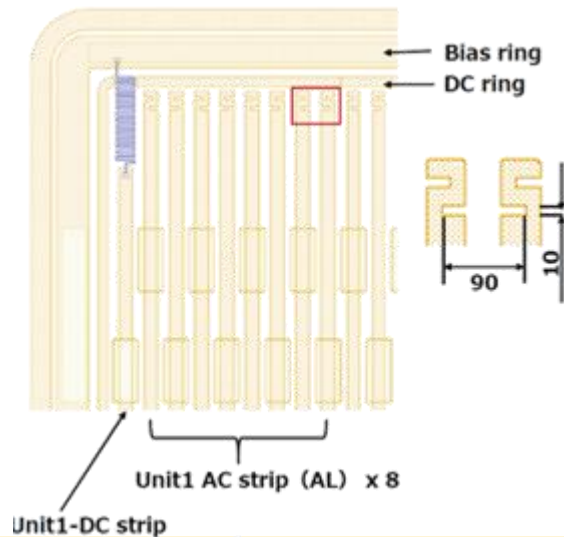
**Pad type sensor** (4x 450umx450um)

KEK-ACLG-4PAD-AL



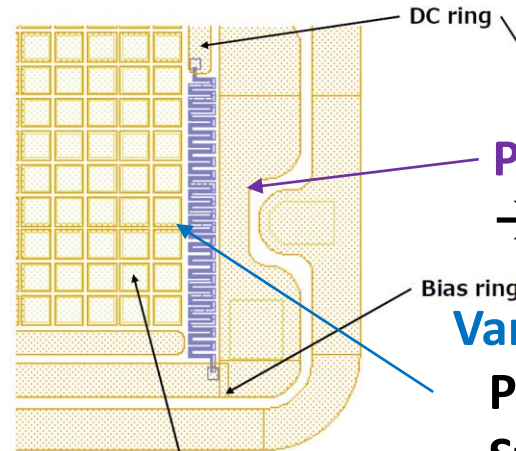
Confidential AC PAD (AL 500□) x 4

**Strip type sensor** (16x 80um pitch)



**Pixel type sensor** (14x14 50umx50um)

KEK-ACLG-PIXEL-42



AC PAD (AL 42□) x 196

Poly-si resistor between DC ring and Bias ring(GND)  
→ To free up charge in n+.

Varied Al size (AC coupling capacitance size)

Pixel : 42/38/34/30 um width/length

Strip : 47/42/37/32 um width

Varied n+ and p+ doping concentration

		N+ doping concentration / resistivity		
		C(Ax10 resistivity)	B(Ax3.3 resistivity)	A (~DC-LGAD)
p+ doping	P+ doping concentration	3 (high)	B-3	A-3
		2 (mid)	B-2	A-2
		1 (low)	B-1	
		n+ doping		



# Electrical Properties – IV curve

Varied n+ and p+ doping concentration

		N+ doping concentration / resistivity		
		C(Ax10 resistivity)	B(Ax3.3 resistivity)	A (~DC-LGAD)
P+ doping concentration	3 (high)		B-3	A-3
	2 (mid)	C-2	B-2	A-2
	1 (low)	C-1	B-1	

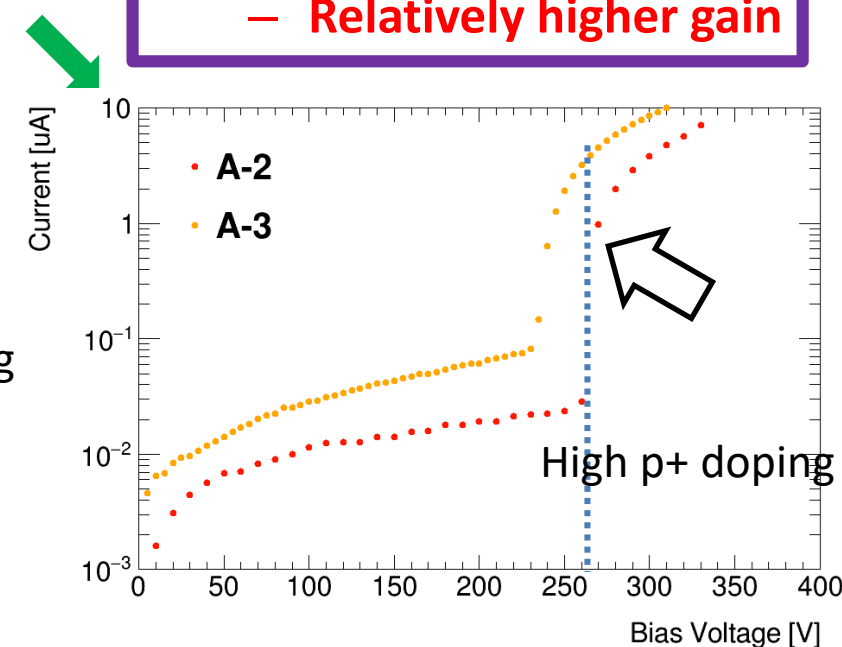
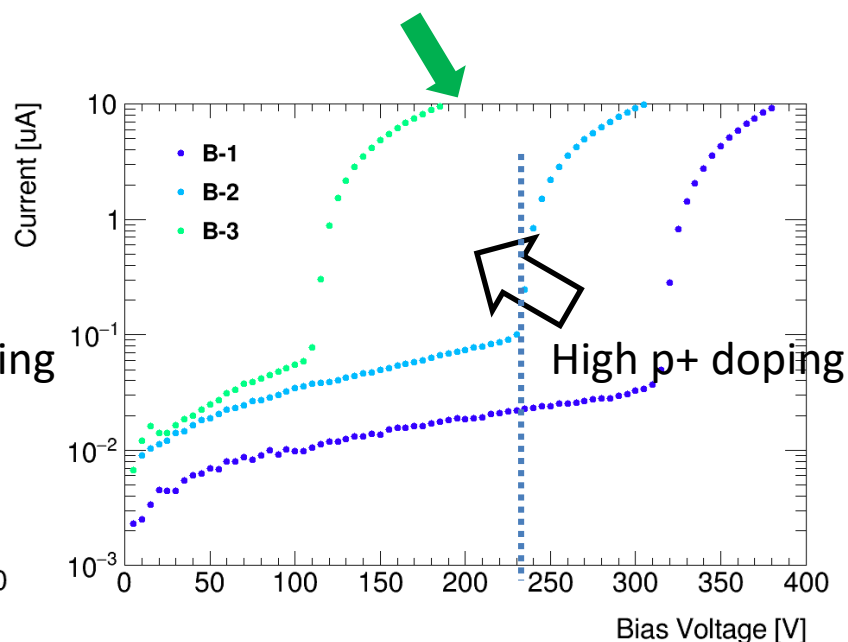
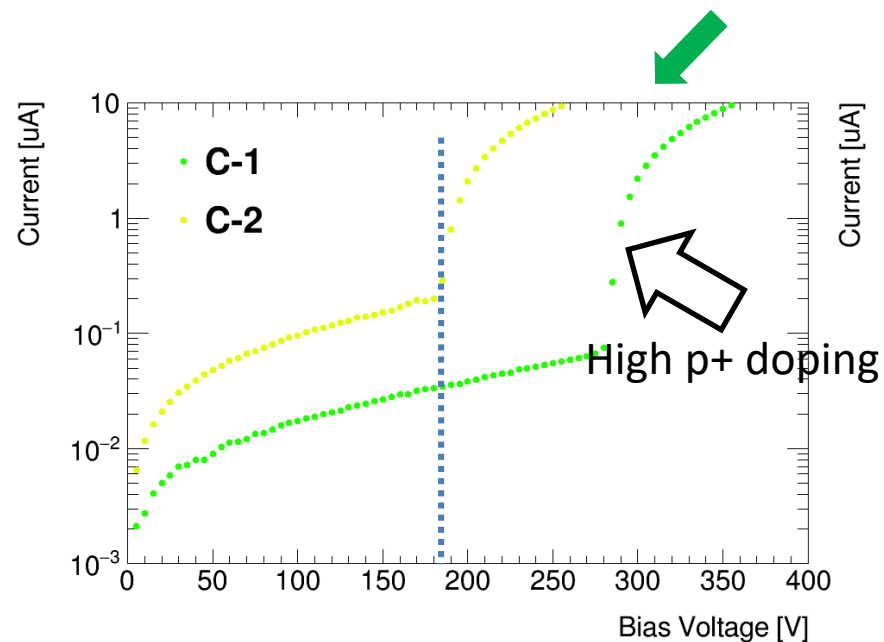
Higher Gain/earlier break in case :

- Higher p+ doping
- Lower n+ doping



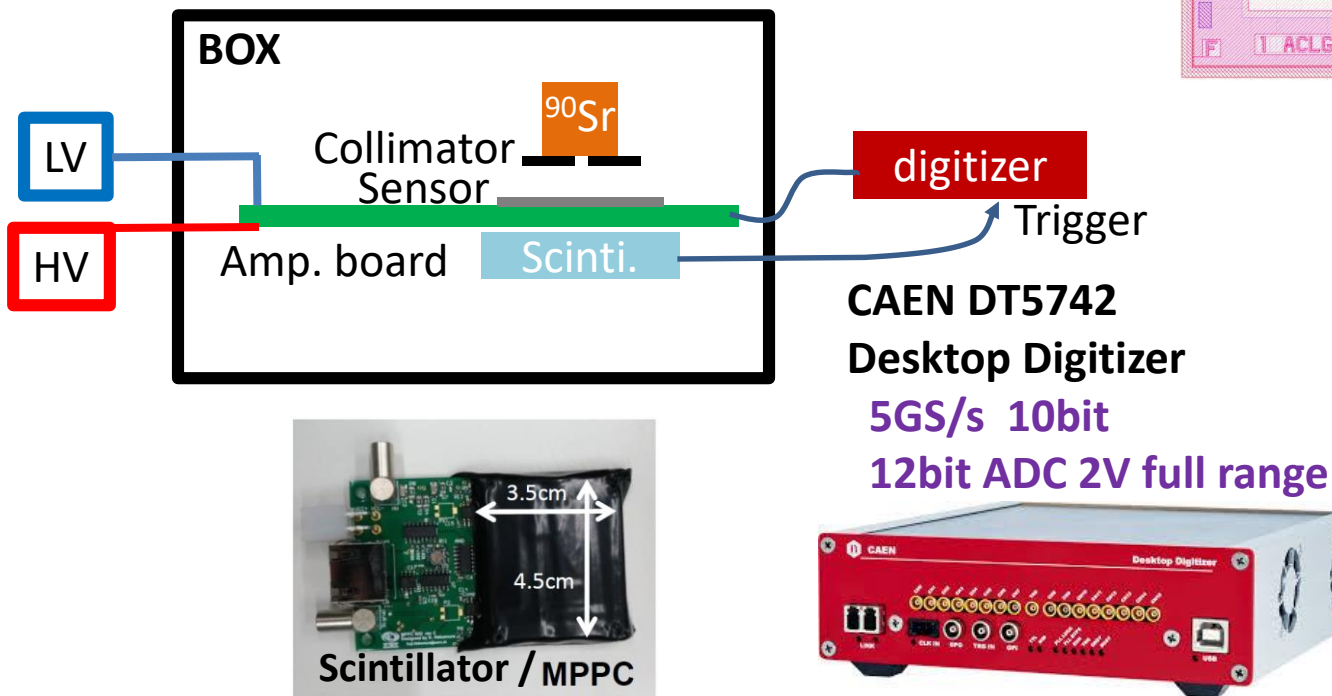
C-2 type should be :

- Smaller crosstalk
- Relatively higher gain

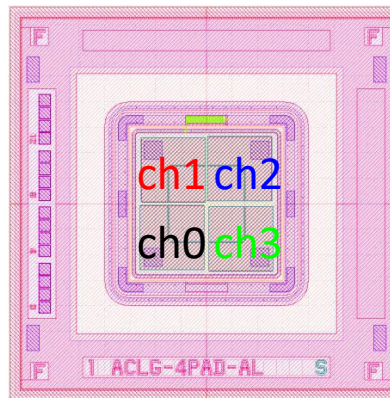


# Pulse shape measurement

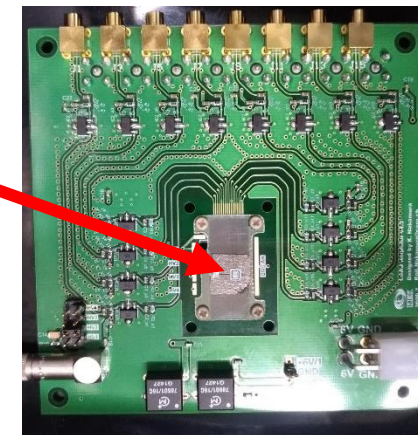
- To detect signal from AC-LGAD
  - Used  $^{90}\text{Sr}$   $\beta$  source
  - Discrete Amp has been designed by Fermilab and modified/produced at KEK.
  - Pulse detected by CAEN DT5742 digitizer
  - Triggered by Scintillator with MPPC readout



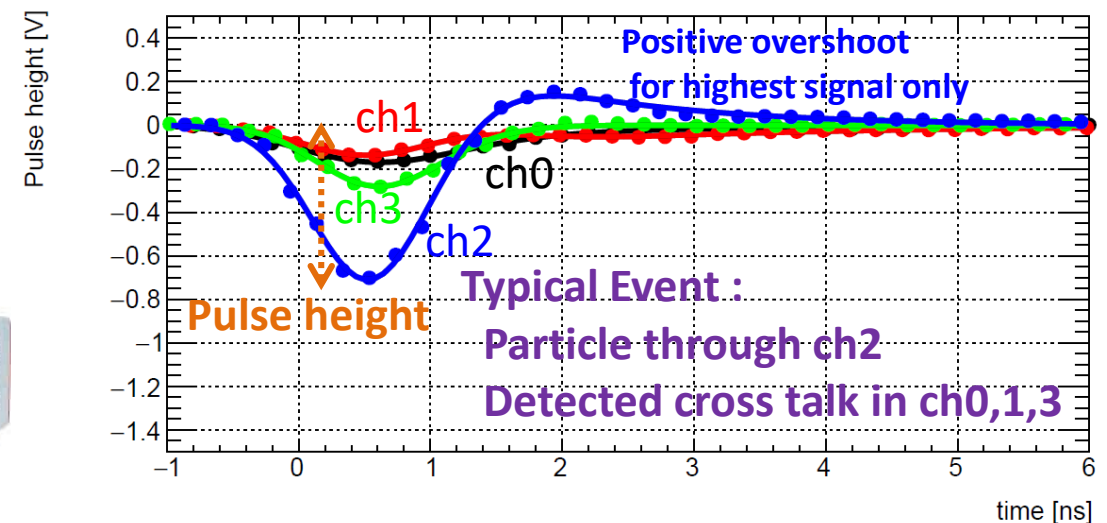
Pad Sensor



KEK  
16 ch Discrete Amp.



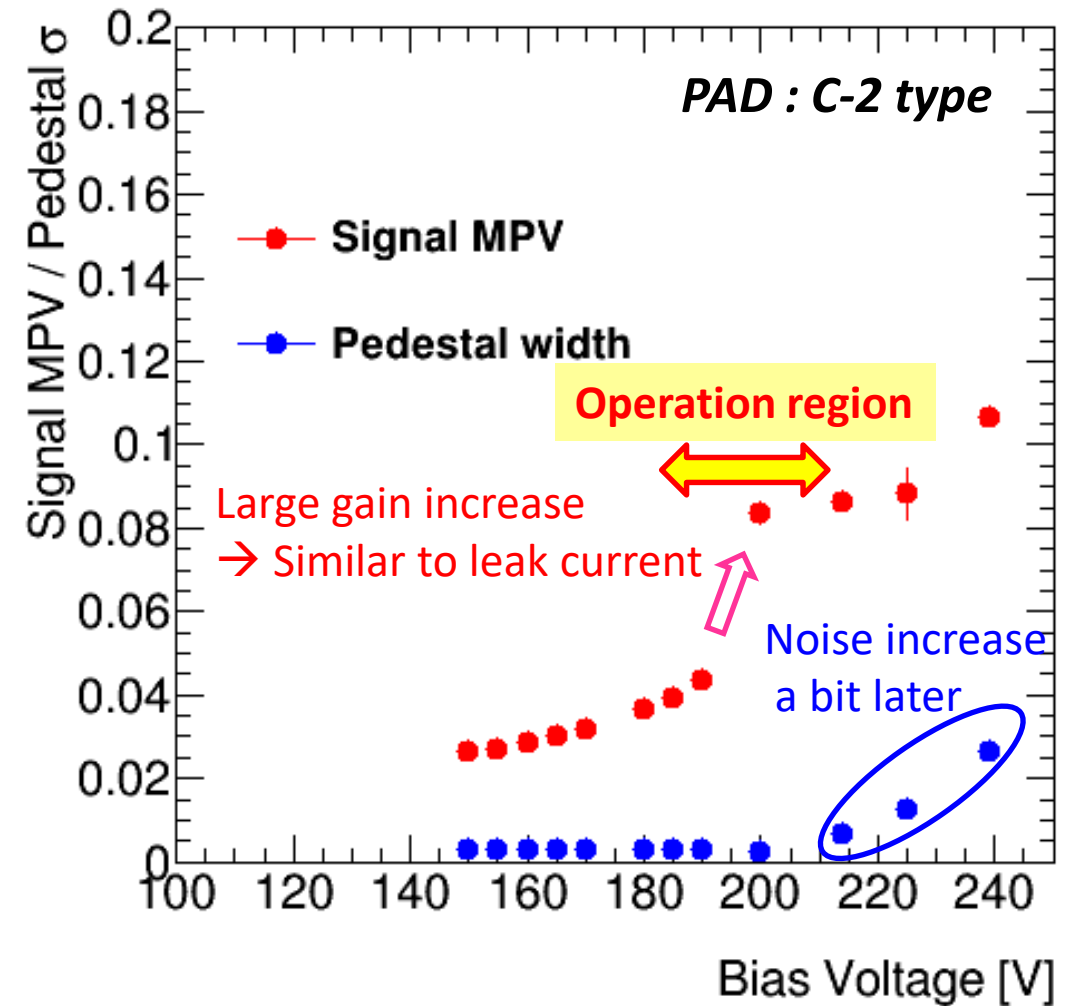
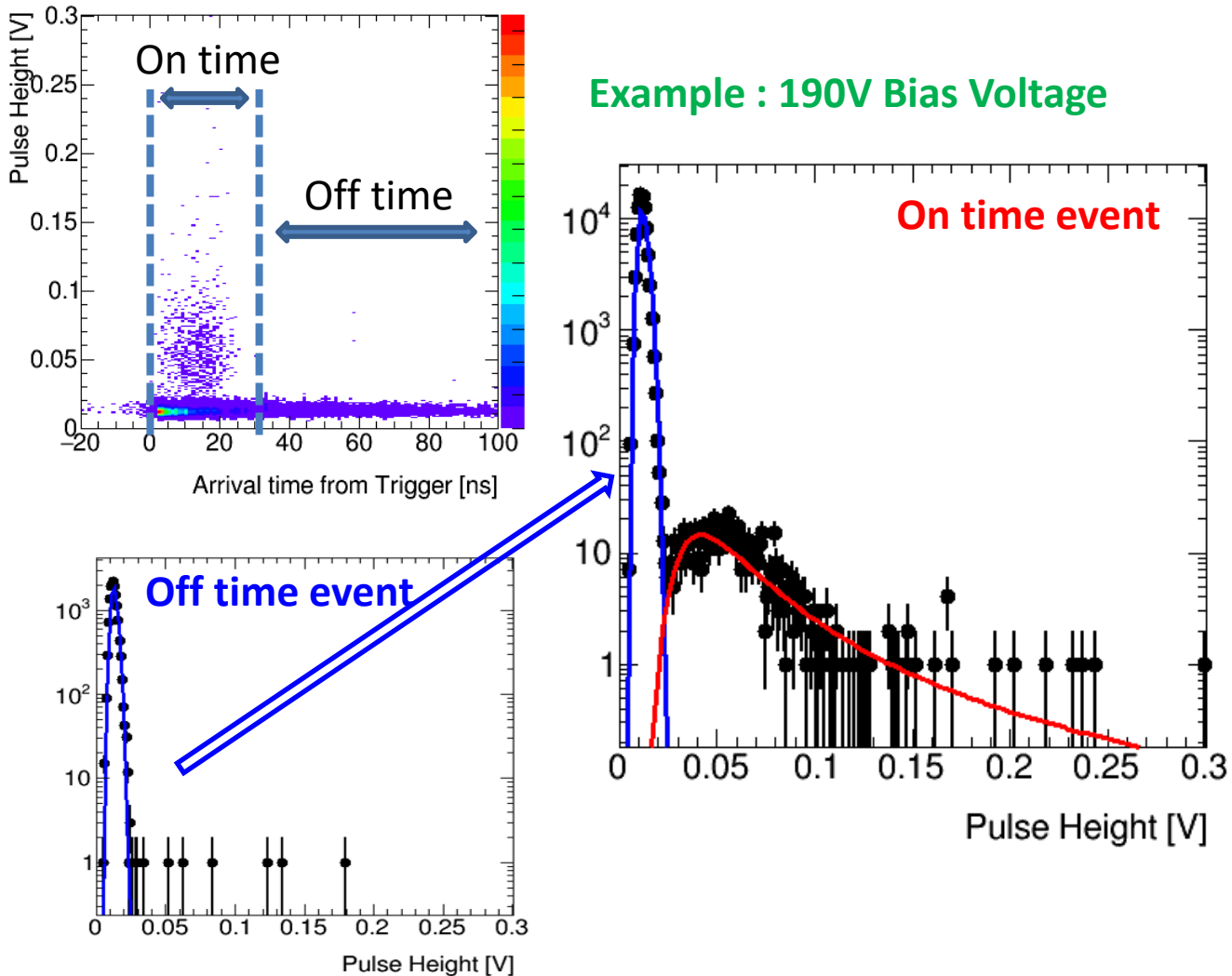
Fermilab  
16 ch Discrete Amp.





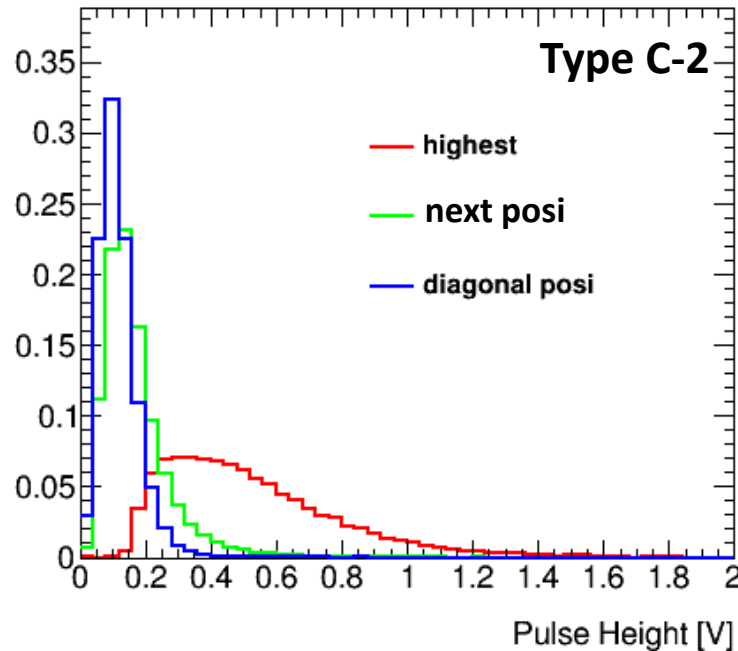
# Pulse Height and Bias Voltage dependence

Pedestal distribution is evaluated from off timing region

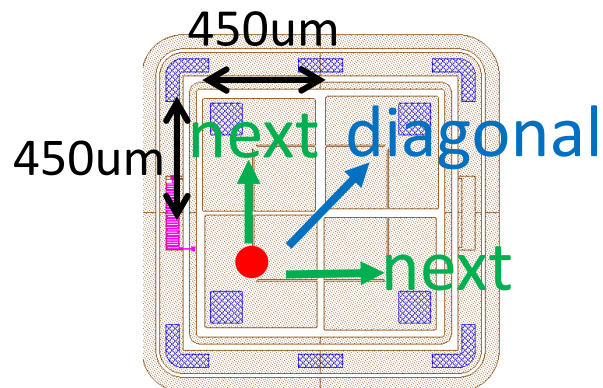


# Pulse height distribution and Crosstalk

Pulse height

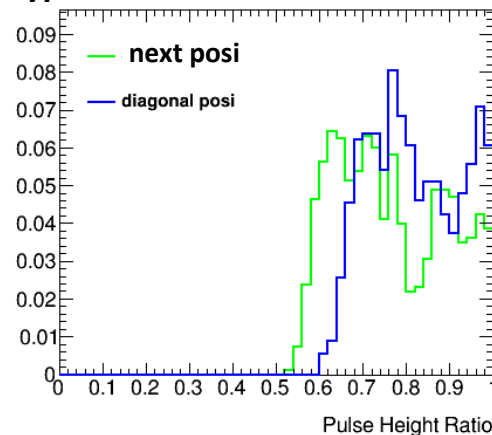


- Pulse height distribution
  - type C-2 (x10 n+ resistivity) show good separation of signal and crosstalk.
- Cross talk depends on n+ resistivity
  - Higher resistivity have smaller crosstalk
  - **~20% crosstalk for type C (x10 n+ resistivity)**

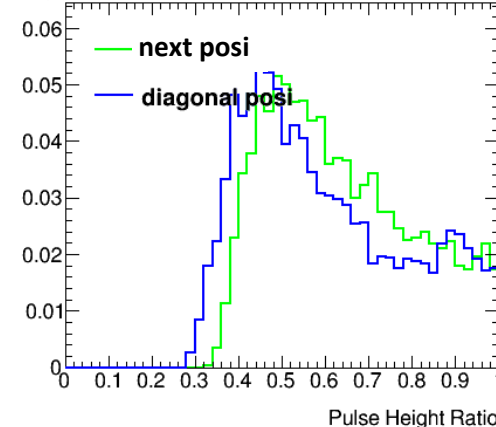


Pulse height ratio to the Leading pulse height

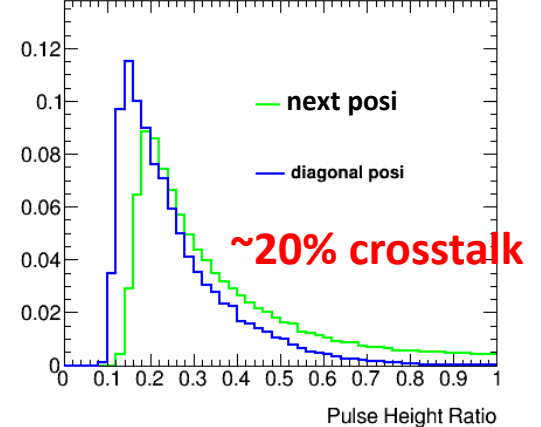
Type A : same n+ res to DC LGAD



Type B : x3.3 n+ resistivity



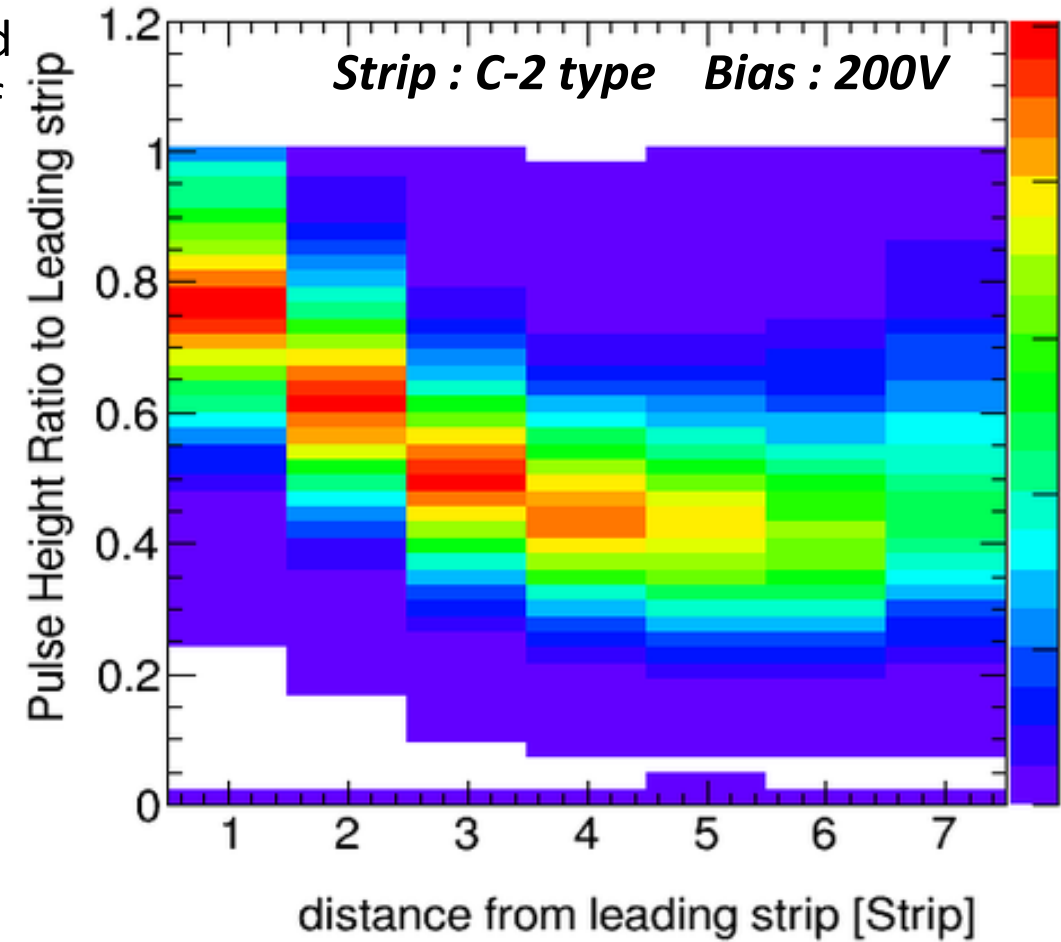
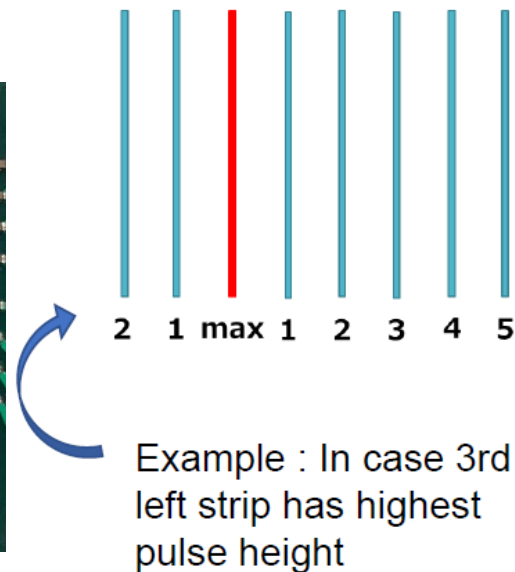
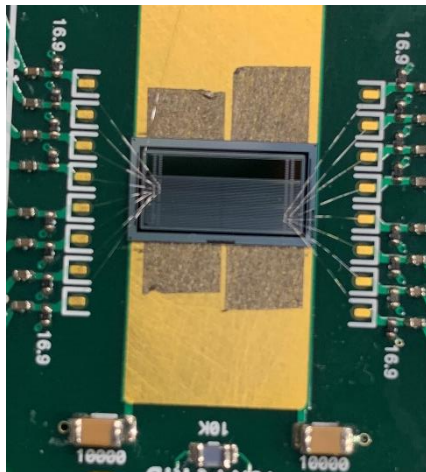
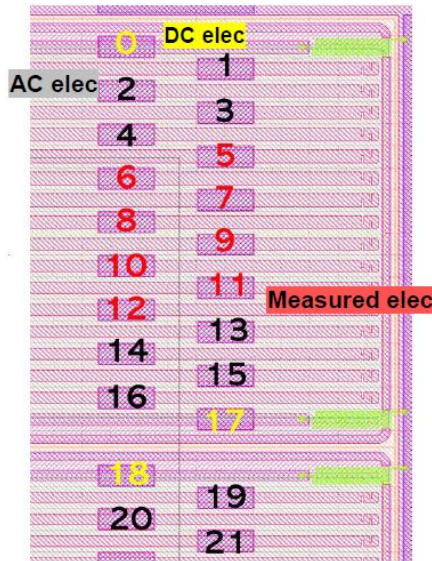
Type C : x10 n+ resistivity



# Distance dependence of Crosstalk

- Crosstalk should depend on distance of electrode.
  - To check the dependence, **strip sensor** (80um pitch) is used
  - Pulse height ratio to leading strip is plotted as a function of distance (unit of strips)
  - ~75% @ 80um, ~62% @ 160um distance.**
  - The strip where particle passed can be identified, but better to have smaller crosstalk.** → will test higher n+ resistivity

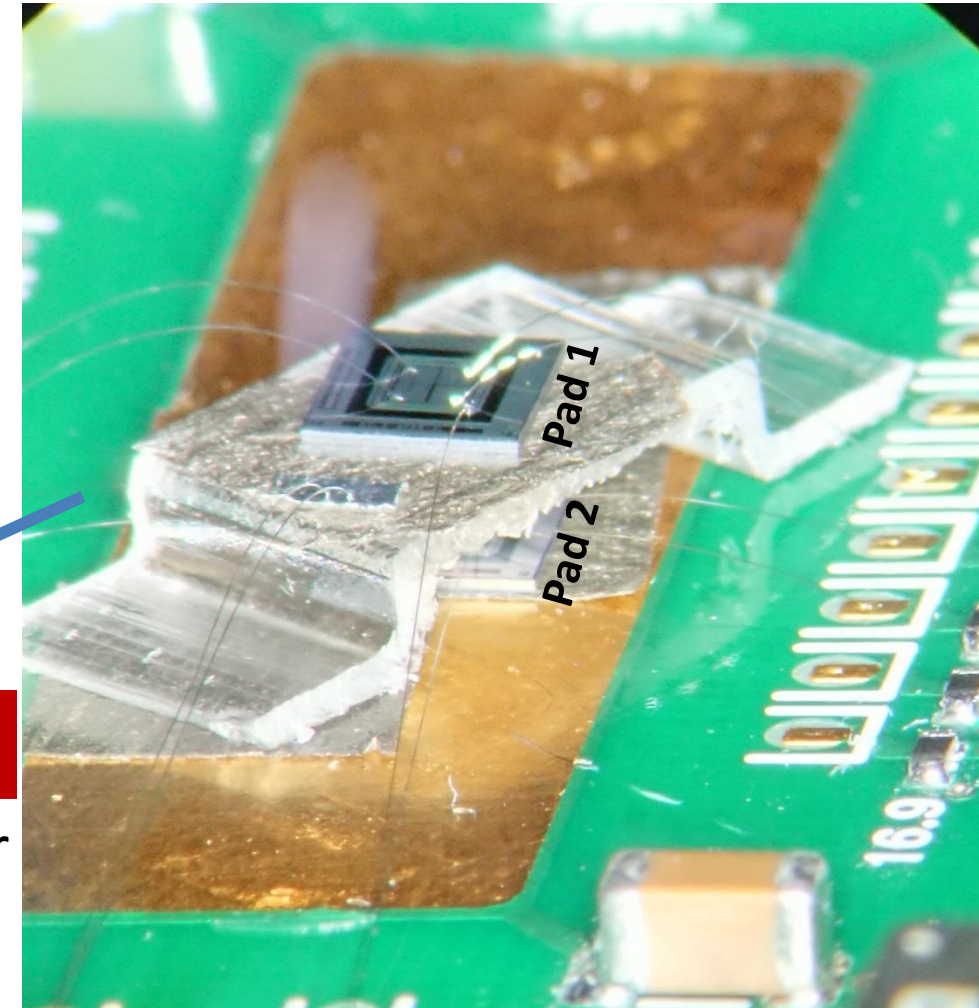
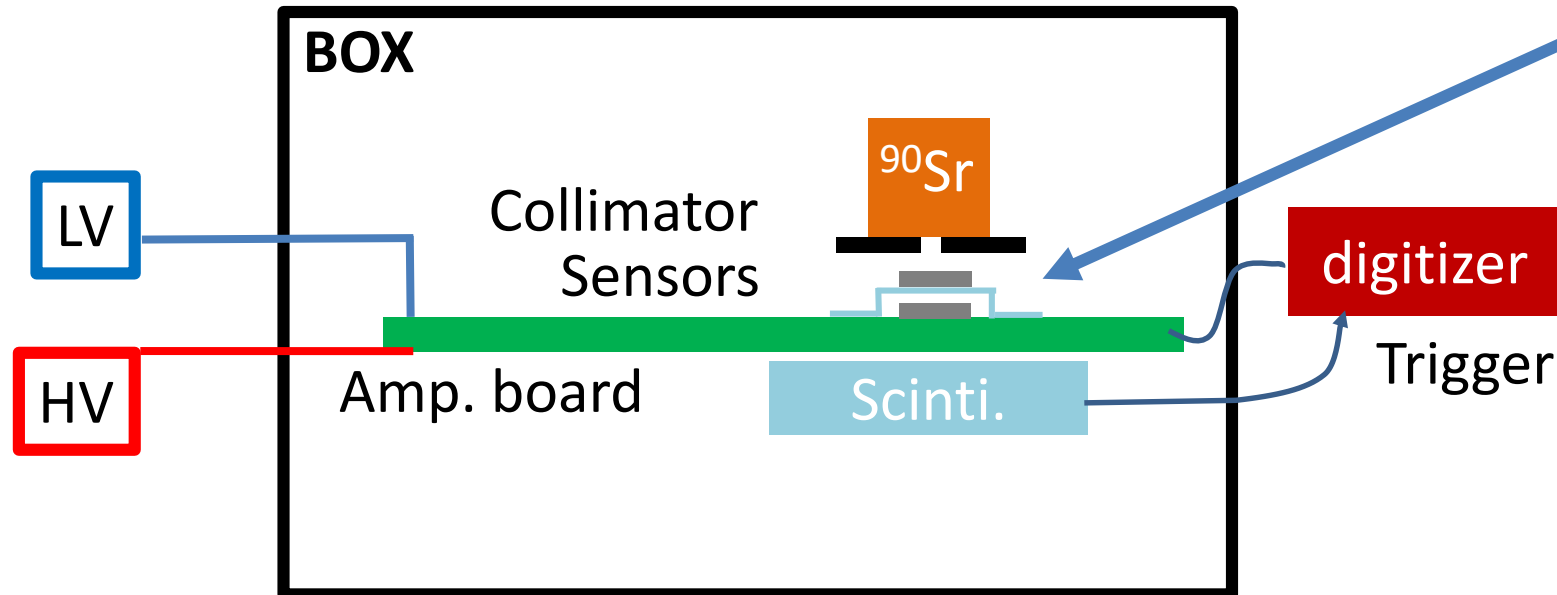
Strip Sensor



# Time resolution

- To evaluate timing resolution, two same type of pad sensors are stacked interleaved by using plastic piece.

- Sigma of time difference :  $\sigma(T_1 - T_2) = \sqrt{(\sigma_1)^2 + (\sigma_2)^2}$
- In case two same type sensors :  $\sigma_t = \sigma(T_1 - T_2) / \sqrt{2}$

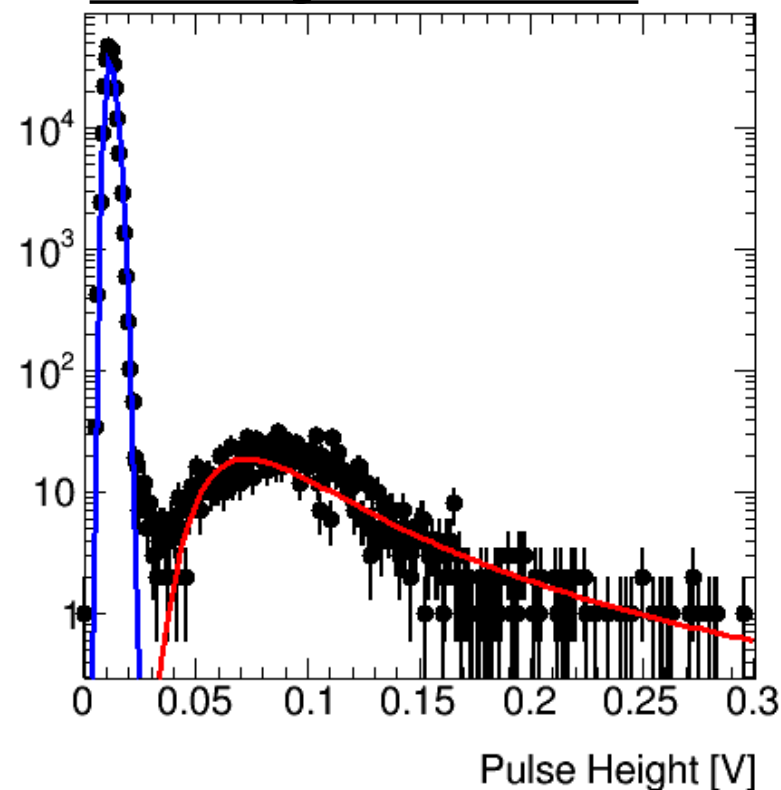




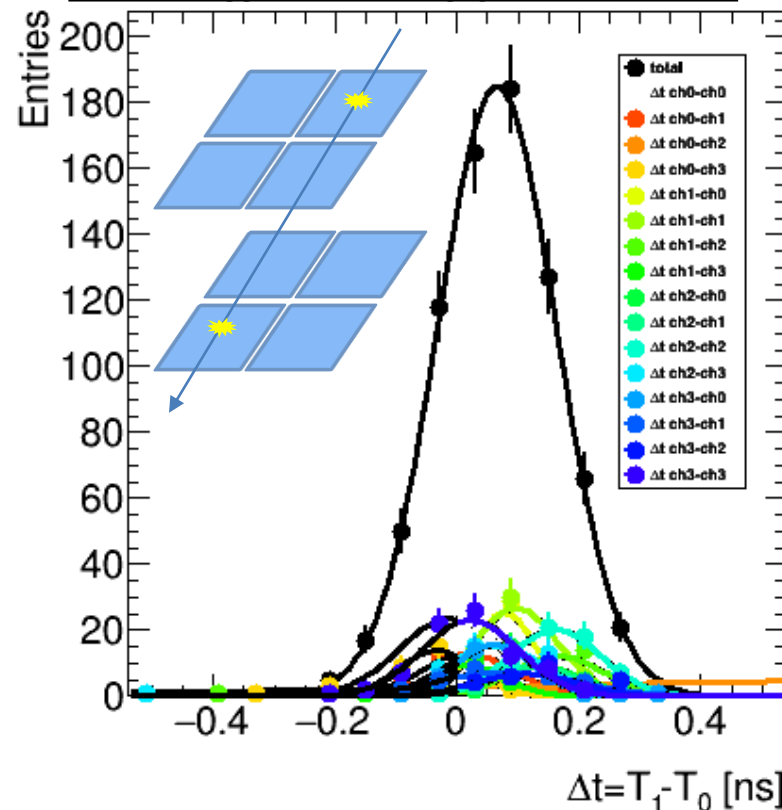
# Time resolution

- Time difference has been calculated separately for all combination of channels in top and bottom channel then combined.
- Evaluated ~45ps time resolution at 200V.**

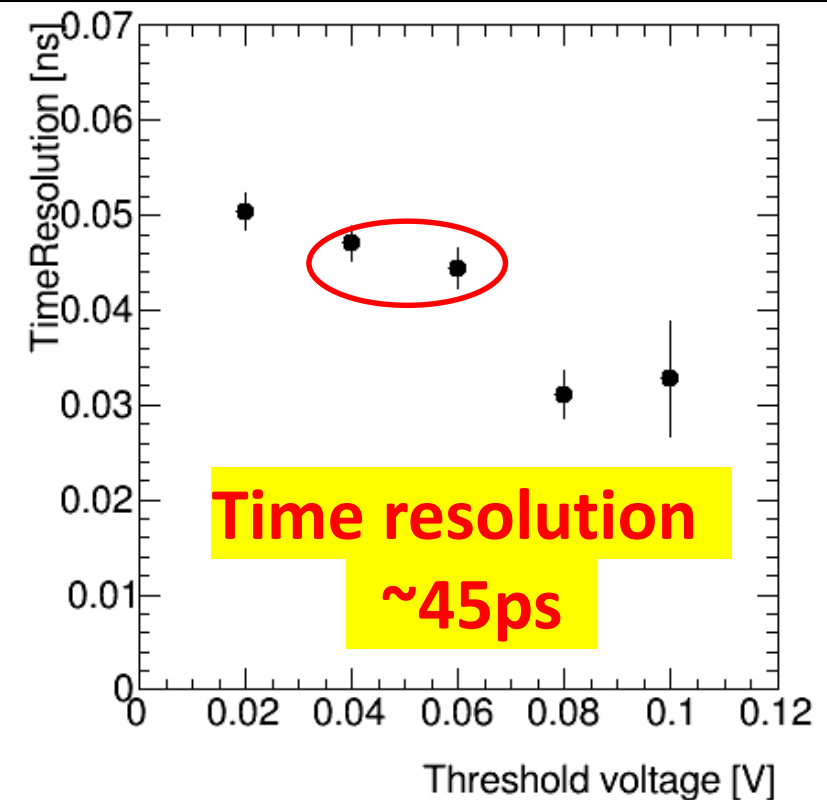
Pulse Height Distribution



Time difference of pad 1 and 2



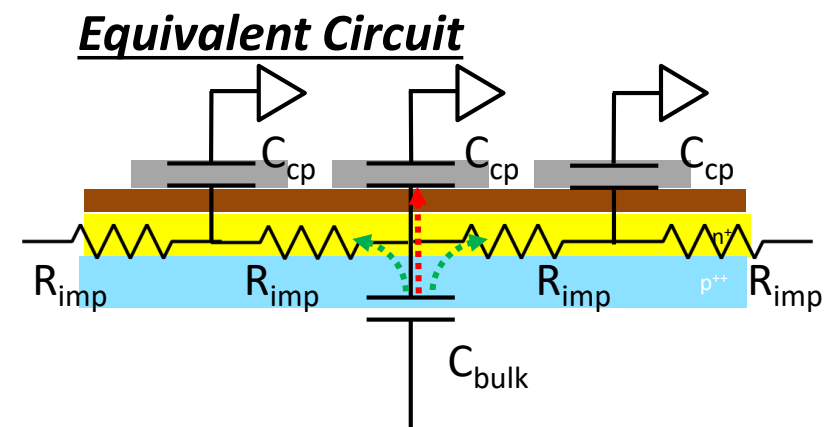
Timing resolution with certain threshold



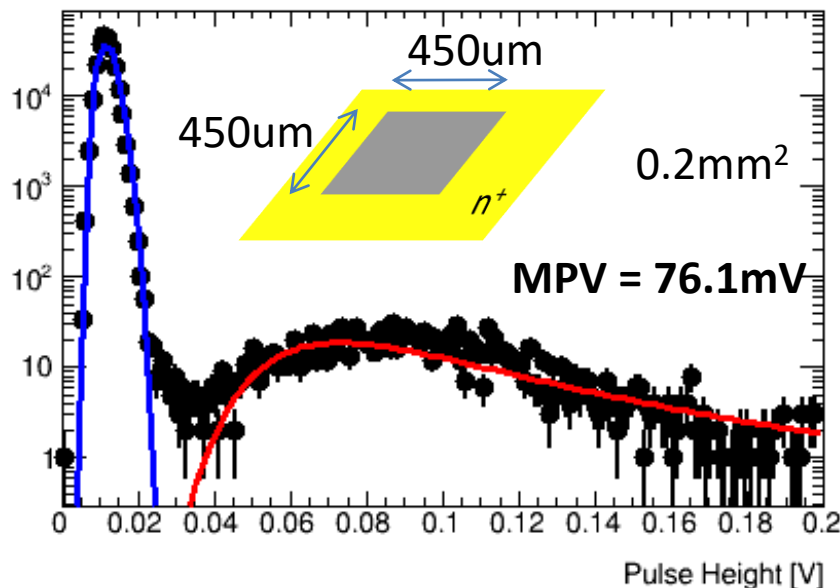


# Coupling capacitance and signal size

- Even the same bias voltage (200V), different pulse height signal detected in Pad and Strip detectors.
  - The same n+ and p+ shape for both detector (uniform for all active area). Then signal split to electrode and n+ imp.
  - Smaller Coupling capacitance may attenuation the signal.**
    - Large signal difference of strip and pad sensors indicate  $1/\omega C_{cp} \gg R_{imp}$   
 $\rightarrow$  Larger  $R_{imp}$  should help to have larger signal?



## Pad Sensor



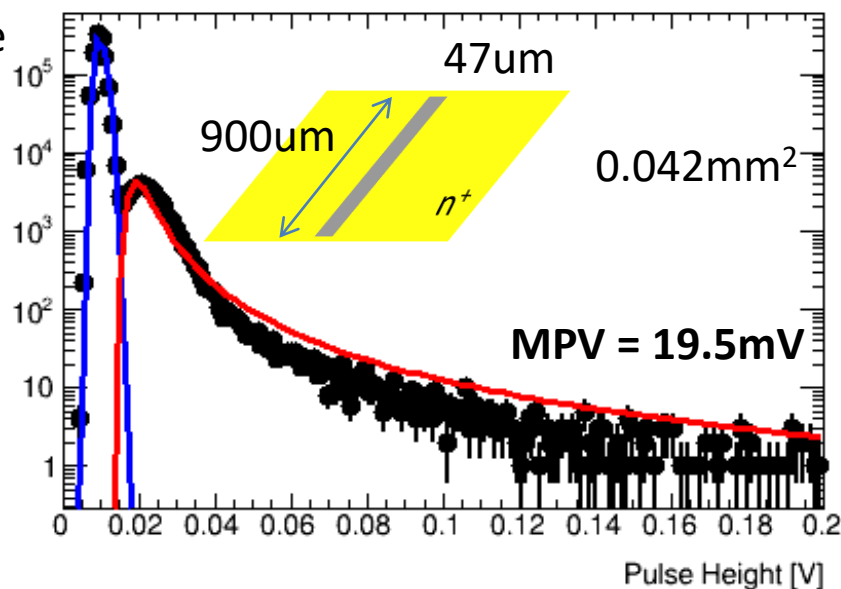
Capacitance

x4.5

Signal

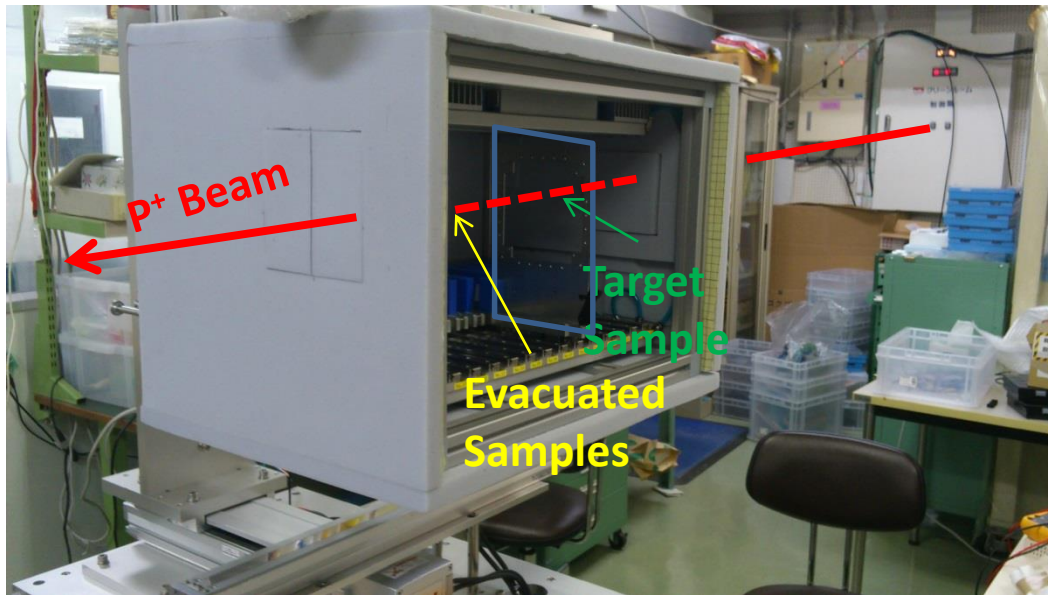
x3.9

## Strip Sensor



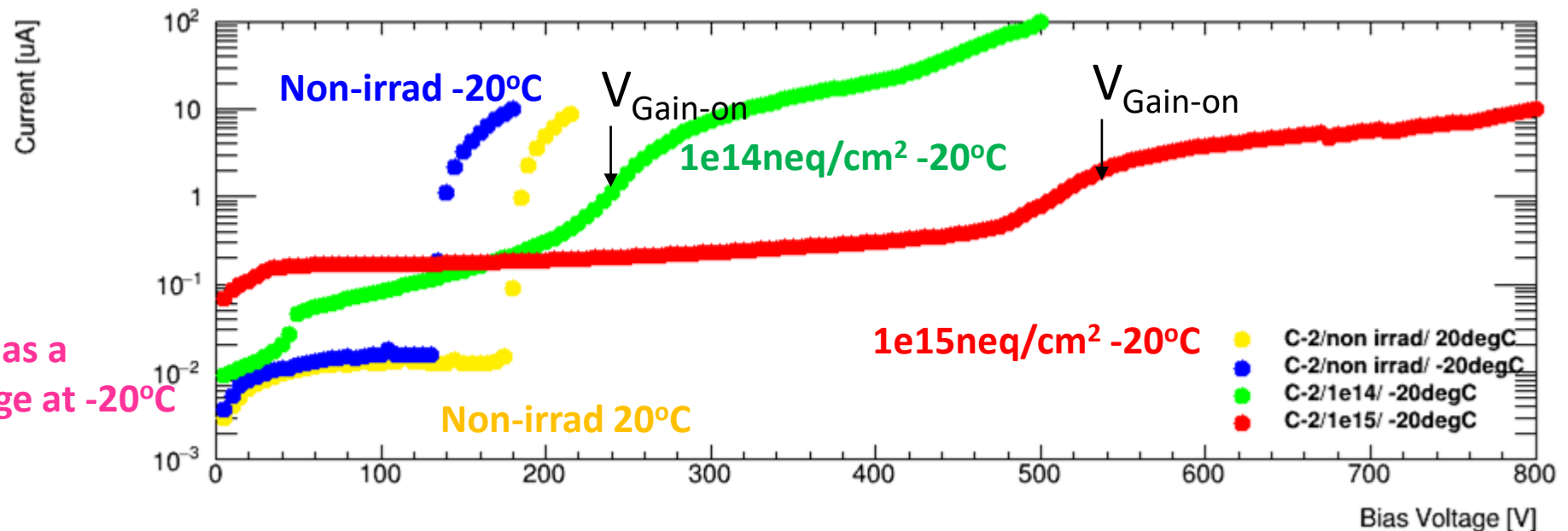
# Proton Irradiation Facility in Japan

- CYRIC@Tohoku Univ. is an irradiation facility with 70MeV proton beam ( $\sim 1\mu\text{A}$ ).
  - This allows irradiation of silicon sensor of 3mm thickness in total (3% E loss).
  - Operated at  $-15^\circ\text{C}$  temperature with dry  $\text{N}_2$  gas.
- Remotely controllable X-Y stage and “push-pull” mechanism are implemented to the machine.
  - Choose to irradiate one or more target samples out of 15 pre-installed samples.
- Scanned over full sensor range during irradiation.
- **Actual Fluence difference relative to the target fluence is within  $\sim 10\%$ .**



# Electrical test after Irradiation

- Irradiated sensors at  $1e14\text{neq/cm}^2$  and  $1e15\text{neq/cm}^2$  and tested I-V performance.
- Gain-on voltage increased to  **$\sim 220\text{V}$  @  $1e14\text{neq/cm}^2$**  and  **$550\text{V}$  @  $1e15\text{neq/cm}^2$** ; they still seem to have gain.

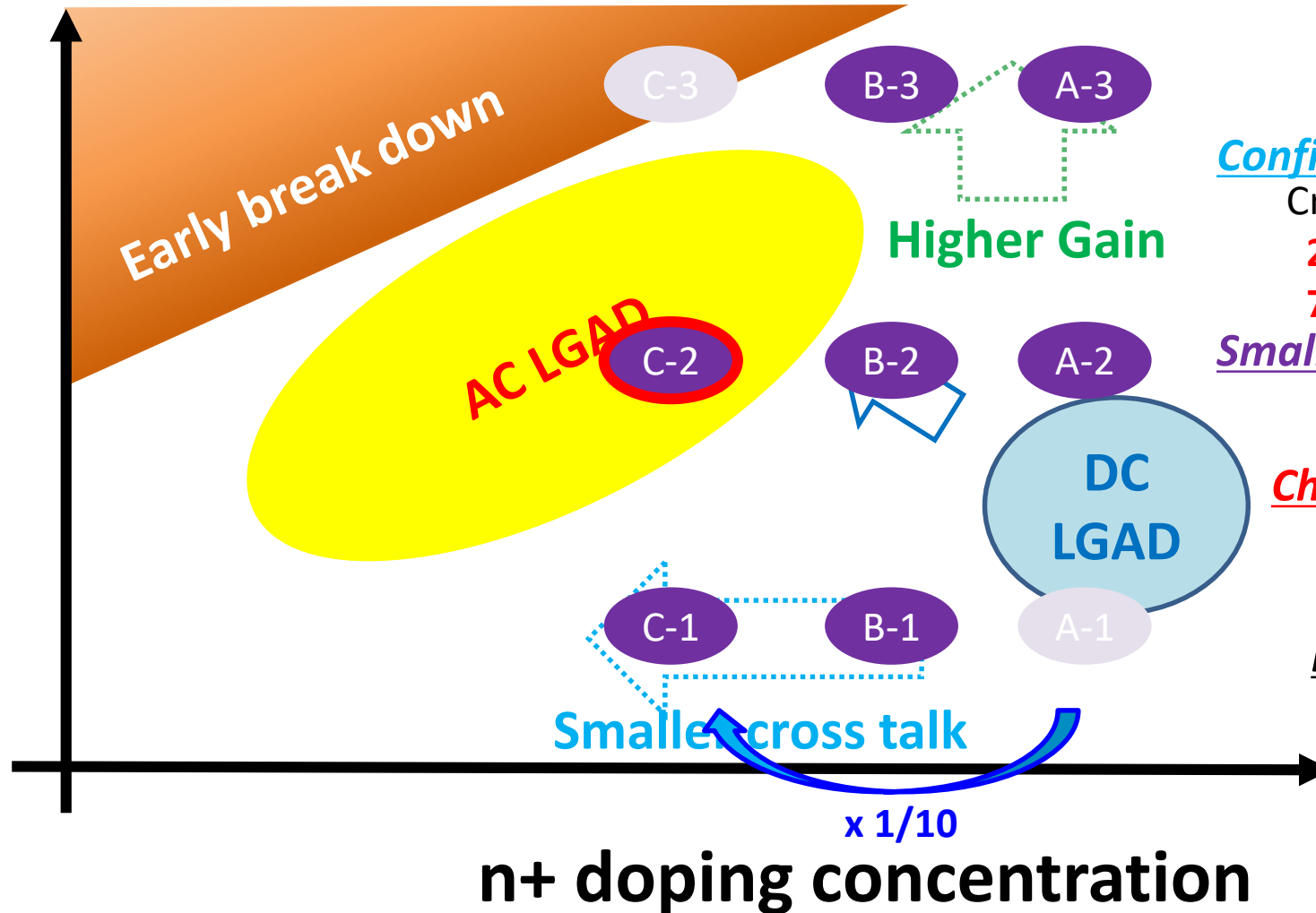


Note: Non-irrad sample has a lower gain-on voltage at -20°C  
 $190\text{V} \rightarrow 140\text{V}$

# Conclusion & Plan

p+ doping concentration

Parameter space for doping concentration



fabricated at HPK

Working well as LGAD detector  
with spatial resolution

Confirmed smaller crosstalk in lower n+ doping

Cross talk : x10 n+ resistivity sample (C-2 type)

20% to next pad

75% (62%) to next (next-next) 80um pitch strip

Smaller Electrode makes smaller signal

Due to smaller Coupling Capacitance

To be improved.

Checked timing resolution for C-2 type pad

Evaluated ~45ps timing resolution  
at 200V bias voltage.

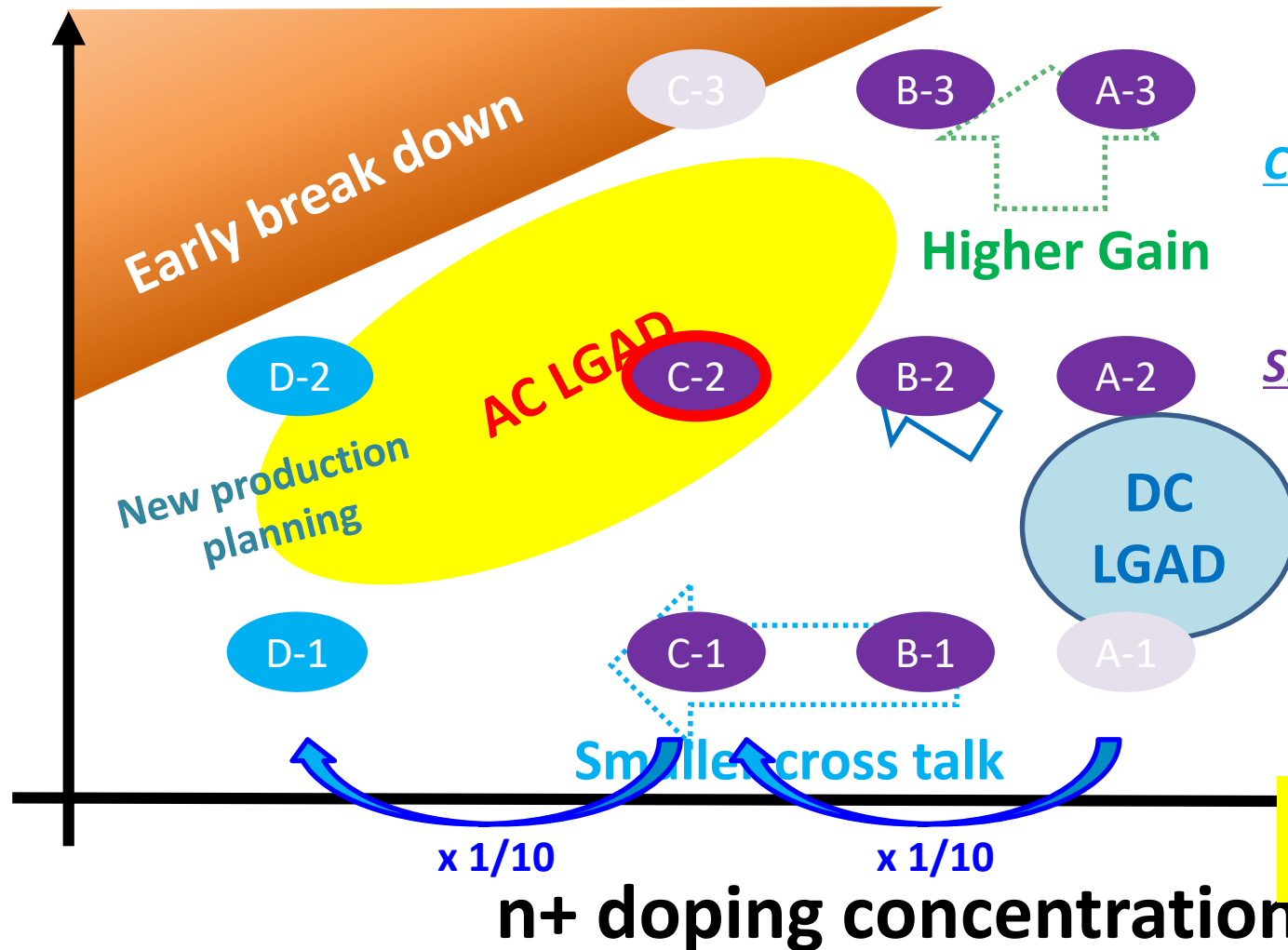
Irradiated sample tested

up to  $1e15 \text{ neq/cm}^2$ , and still have gain

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New production planned further 1/10 n+ doping  
Thinner Oxide to make higher Coupling Capacitor



# backup

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# Temperature dependent IV curve

- Changed temperature from  $-30^{\circ}\text{C}$  to  $24^{\circ}\text{C}$

